- Complete PWM Power Control Circuitry
- Uncommitted Outputs for 200-mA Sink or Source Current
- Output Control Selects Single-Ended or Push-Pull Operation
- Internal Circuitry Prohibits Double Pulse at Either Output
- Variable Dead Time Provides Control Over Total Range
- Internal Regulator Provides a Stable 5-V Reference Supply With 5% Tolerance
- Circuit Architecture Allows Easy Synchronization

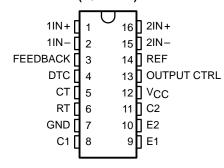
## description

The TL494 incorporates on a single monolithic chip all the functions required in the construction of a pulse-width-modulation control circuit. Designed primarily for power supply control, this device offers the systems engineer the flexibility to tailor the power supply control circuitry to a specific application.

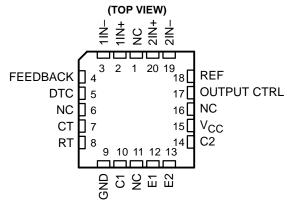
The TL494 contains two error amplifiers, an on-chip adjustable oscillator, a dead-time control (DTC) comparator, a pulse-steering control flip-flop, a 5-V, 5%-precision regulator, and output-control circuits.

The error amplifiers exhibit a common-mode voltage range from -0.3~V to  $V_{CC}~-2~V$ . The dead-time control comparator has a fixed offset that provides approximately 5% dead time. The on-chip oscillator may be bypassed by terminating RT to the reference output and providing a sawtooth input to CT, or it may drive the common circuits in synchronous multiple-rail power supplies.

# TL494C, TL494I... D, N, OR PW PACKAGE TL494M... J PACKAGE (TOP VIEW)



#### TL494M ... FK PACKAGE



NC - No internal connection

#### **FUNCTION TABLE**

INPUT TO OUTPUT CTRL	OUTPUT FUNCTION
V <sub>I</sub> = GND	Single-ended or parallel output
V <sub>I</sub> = V <sub>ref</sub>	Normal push-pull operation

#### **AVAILABLE OPTIONS**

		PAC	KAGED DEVICE	S		CHIP
TA	SURFACE MOUNT (D)†	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)	SHRINK SMALL OUTLINE (PW) <sup>‡</sup>	FORM (Y)
0°C to 70°C	TL494CD		_	TL494CN	TL494CPW	TL494Y
-40°C to 85°C	TL494ID	_	_	TL494IN	_	_
-55°C to 125°C	_	TL494MFK	TL494MJ	_	_	_

<sup>&</sup>lt;sup>†</sup> The D package is available taped and reeled. Add R suffix to device type (e.g., TL494CDR).

<sup>&</sup>lt;sup>‡</sup>The PW package is only available left-end taped and reeled.



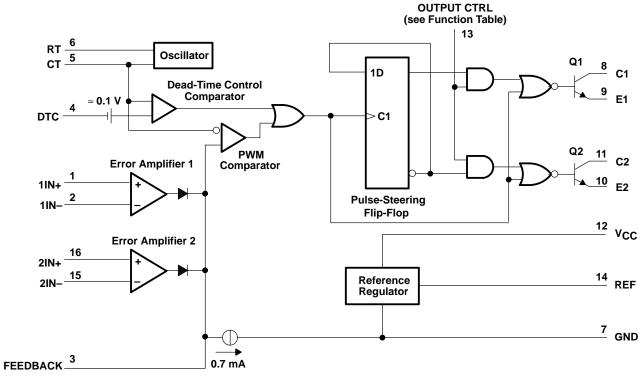
SLVS074A - JANUARY 1983 - REVISED AUGUST 1995

## description (continued)

The uncommitted output transistors provide either common-emitter or emitter-follower output capability. The TL494 provides for push-pull or single-ended output operation, which may be selected through the output-control function. The architecture of this device prohibits the possibility of either output being pulsed twice during push-pull operation.

The TL494C is characterized for operation from  $0^{\circ}$ C to  $70^{\circ}$ C. The TL494I is characterized for operation from  $-40^{\circ}$ C to  $85^{\circ}$ C. The TL494M is characterized for operation from  $-55^{\circ}$ C to  $125^{\circ}$ C.

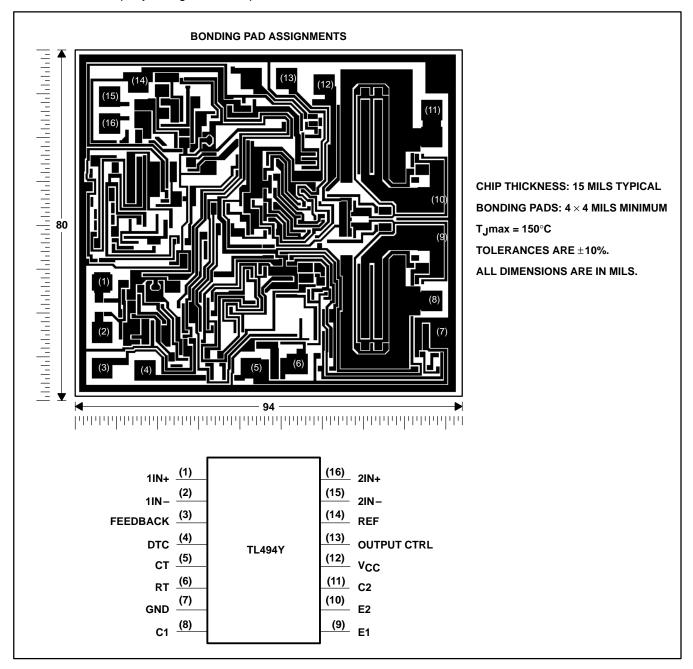
## functional block diagram



NOTE A. The terminal numbers indicated apply only to the D, J, N, and PW packages.

## **TL494Y chip information**

This chip, when properly assembled, display characteristics similar to the TL494C. Thermal compression or ultrasonic bonding may be used on the doped aluminum bonding pads. The chips may be mounted with conductive epoxy or a gold-silicon preform.



## TL494C, TL494I, TL494M, TL494Y PULSE-WIDTH-MODULATION CONTROL CIRCUITS

SLVS074A – JANUARY 1983 – REVISED AUGUST 1995

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

	TL494C	TL494I	TL494M	UNIT		
Supply voltage, V <sub>CC</sub> (see Note 1)	41	41	41	V		
Amplifier input voltage, V <sub>I</sub>	V <sub>CC</sub> + 0.3	V <sub>CC</sub> + 0.3	V <sub>CC</sub> + 0.3	V		
Collector output voltage, VO	41	41	41	V		
Collector output current, IO	250	250	250	mA		
Continuous total power dissipation	S	ee Dissipation F	ation Rating Table			
Operating free-air temperature range, T <sub>A</sub>	0 to 70	-40 to 85	-55 to 125	°C		
Storage temperature range, T <sub>Stg</sub>	-65 to 150	-65 to 150	-65 to 150	°C		
Case temperature for 60 seconds, T <sub>C</sub> : FK package	_	_	260	°C		
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D, N, or PW package	260	260	_	°C		
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: J package	_	_	300	°C		

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values, except differential voltages, are with respect to the network ground terminal.

#### **DISSIPATION RATING TABLE**

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR	DERATE ABOVE T <sub>A</sub>	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING	T <sub>A</sub> = 125°C POWER RATING
D	900 mW	7.6 mW/°C	25°C	558 mW	444 mW	_
FK	1375 mW	11.0 mW/°C	25°C	880 mW	715 mW	275 mW
J	1375 mW	11.0 mW/°C	25°C	880 mW	715 mW	275 mW
N	1000 mW	9.2 mW/°C	41°C	733 mW	595 mW	_
PW	700 mW	5.6 mW/°C	25°C	448 mW	_	_

## recommended operating conditions

	TL4	94C	TL4	1941	TL494M		UNIT
	MIN	MAX	MIN	MAX	MIN	MAX	I UNII
Supply voltage, V <sub>CC</sub>	7	40	7	40	7	40	V
Amplifier input voltage, V <sub>I</sub>	-0.3	V <sub>CC</sub> -2	-0.3	V <sub>CC</sub> -2	-0.3	V <sub>CC</sub> -2	V
Collector output voltage, VO		40		40		40	V
Collector output current (each transistor)		200		200		200	mA
Current into feedback terminal		0.3		0.3		0.3	mA
Oscillator frequency, fosc	1	300	1	300	1	300	kHz
Timing capacitor, C <sub>T</sub>	0.47	10000	0.47	10000	0.47	10 000	nF
Timing resistor, R <sub>T</sub>	1.8	500	1.8	500	1.8	500	kΩ
Operating free-air temperature, T <sub>A</sub>	0	70	-40	85	-55	125	°C

SLVS074A - JANUARY 1983 - REVISED AUGUST 1995

electrical characteristics over recommended operating free-air temperature range,  $V_{CC} = 15 \text{ V}$ , f = 10 kHz (unless otherwise noted)

#### reference section

242445	TEST SOURITIONS!	TL494C, TL494I			TL494M			
PARAMETER	TEST CONDITIONS†	MIN	TYP <sup>‡</sup>	MAX	MIN	TYP‡	MAX	UNIT
Output voltage (REF)	I <sub>O</sub> = 1 mA	4.75	5	5.25	4.75	5	5.25	V
Input regulation	V <sub>CC</sub> = 7 V to 40 V		2	25		2	25	mV
Output regulation	I <sub>O</sub> = 1 mA to 10 mA		1	15		1	15	mV
Output voltage change with temperature	$\Delta T_A = MIN \text{ to MAX}$		2	10		2	30*	mV/V
Short-circuit output current§	REF = 0 V		25			-25		mA

<sup>\*</sup> On products compliant to MIL-STD-883, Class B, this parameter is not production tested.

## oscillator section, $C_T$ = 0.01 $\mu$ F, $R_T$ = 12 $k\Omega$ (see Figure 1)

24244577	TEST CONDITIONS†	TL494C, TL494I			TL494M			
PARAMETER	TEST CONDITIONS!	MIN	TYP‡	MAX	MIN	TYP‡	MAX	UNIT
Frequency			10			10		kHz
Standard deviation of frequency¶	All values of $V_{CC}$ , CT, RT, and $T_A$ constant		100			100		Hz/kHz
Frequency change with voltage	$V_{CC} = 7 \text{ V to } 40 \text{ V}, \qquad T_{A} = 25^{\circ}\text{C}$		1			1		Hz/kHz
Frequency change with temperature#	$\Delta T_A = MIN \text{ to MAX}$			10			10*	Hz/kHz

<sup>\*</sup> On products compliant to MIL-STD-883, Class B, this parameter is not production tested.

$$\sqrt{\frac{\sum_{n=1}^{N} (x_n - \overline{X})^2}{N-1}}$$

#### error amplifier section (see Figure 2)

PARAMETER	TEST CON	TEST CONDITIONS			TL494C, TL494I TL494M			
			MIN	TYP <sup>‡</sup>	MAX			
Input offset voltage	V <sub>O</sub> (FEEDBACK) = 2.5 V			2	10	mV		
Input offset current	V <sub>O</sub> (FEEDBACK) = 2.5 V			25	250	nA		
Input bias current	V <sub>O</sub> (FEEDBACK) = 2.5 V			0.2	1	μΑ		
Common-mode input voltage range	V <sub>CC</sub> = 7 V to 40 V		-0.3 to V <sub>CC</sub> -2			V		
Open-loop voltage amplification	$\Delta V_O = 3 \text{ V}, \qquad \text{R}_L = 2 \text{ k}\Omega,$	$V_0 = 0.5 \text{ V to } 3.5 \text{ V}$	70	95		dB		
Unity-gain bandwidth	$V_0 = 0.5 \text{ V to } 3.5 \text{ V},$	$R_L = 2 k\Omega$		800		kHz		
Common-mode rejection ratio	$\Delta V_O = 40 \text{ V}, \qquad T_A = 25^{\circ}\text{C}$		65	80		dB		
Output sink current (FEEDBACK)	$V_{ID} = -15 \text{ mV to } -5 \text{ V},$	V (FEEDBACK) = 0.7 V	0.3	0.7		mA		
Output source current (FEEDBACK)	V <sub>ID</sub> = 15 mV to 5 V,	V (FEEDBACK) = 3.5 V	-2			mA		

<sup>‡</sup> All typical values except for parameter changes with temperature are at T<sub>A</sub> = 25°C.



<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

<sup>‡</sup> All typical values except for parameter changes with temperature are at T<sub>A</sub> = 25°C.

<sup>§</sup> Duration of the short circuit should not exceed one second.

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

<sup>&</sup>lt;sup>‡</sup> All typical values except for parameter changes with temperature are at  $T_A = 25$ °C.

<sup>¶</sup> Standard deviation is a measure of the statistical distribution about the mean as derived from the formula:

<sup>#</sup> Temperature coefficient of timing capacitor and timing resistor not taken into account.

## TL494C, TL494I, TL494M, TL494Y PULSE-WIDTH-MODULATION CONTROL CIRCUITS

SLVS074A - JANUARY 1983 - REVISED AUGUST 1995

electrical characteristics over recommended operating free-air temperature range,  $V_{CC}$  = 15 V, f = 10 kHz,  $T_A$  = 25°C (unless otherwise noted)

#### reference section

DADAMETED	TEST CONDITIONS	•			
PARAMETER	TEST CONDITIONS MIN TYPT MAX		UNIT		
Output voltage (REF)	I <sub>O</sub> = 1 mA		5		V
Input regulation	V <sub>CC</sub> = 7 V to 40 V		2		mV
Output regulation	I <sub>O</sub> = 1 mA to 10 mA		1		mV
Short-circuit output current <sup>‡</sup>	REF = 0 V		25		mA

## oscillator section, $\,$ C $_{T}$ = 0.01 $\mu\text{F},\,$ R $_{T}$ = 12 $k\Omega$ (see Figure 1)

PARAMETER	TEST CONDITIONS		UNIT		
	TEST CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNII
Frequency			10		kHz
Standard deviation of frequency§	All values of V <sub>CC</sub> , CT, RT, and T <sub>A</sub> constant		100		Hz/kHz
Frequency change with voltage	$V_{CC} = 7 \text{ V to } 40 \text{ V},  T_A = 25^{\circ}\text{C}$		1		Hz/kHz

## error amplifier section (see Figure 2)

DARAMETER	TEST SOMBITIONS	TL494Y	
PARAMETER	TEST CONDITIONS	MIN TYPT MAX	UNIT
Input offset voltage	V <sub>O</sub> (FEEDBACK) = 2.5 V	2	mV
Input offset current	V <sub>O</sub> (FEEDBACK) = 2.5 V	25	nA
Input bias current	V <sub>O</sub> (FEEDBACK) = 2.5 V	0.2	μΑ
Open-loop voltage amplification	$\Delta V_O = 3 \text{ V}, \qquad R_L = 2 \text{ k}\Omega, \qquad V_O = 0.5 \text{ V to } 3.5 \text{ V}$	95	dB
Unity-gain bandwidth	$V_O = 0.5 \text{ V to } 3.5 \text{ V},$ $R_L = 2 \text{ k}\Omega$	800	kHz
Common-mode rejection ratio	$\Delta V_{O} = 40 \text{ V}, \qquad T_{A} = 25^{\circ}\text{C}$	80	dB
Output sink current (FEEDBACK)	$V_{ID} = -15 \text{ mV to } -5 \text{ V},$ V (FEEDBACK) = 0.7 V	0.7	mA

<sup>&</sup>lt;sup>†</sup> All typical values except for parameter changes with temperature are at  $T_A = 25$ °C.

$$= \sqrt{\frac{\sum_{n=1}^{N} (x_n - \overline{X})^2}{N-1}}$$

<sup>‡</sup> Duration of the short circuit should not exceed one second.

<sup>§</sup> Standard deviation is a measure of the statistical distribution about the mean as derived from the formula:

SLVS074A - JANUARY 1983 - REVISED AUGUST 1995

## electrical characteristics over recommended operating free-air temperature range, $V_{CC}$ = 15 V, f = 10 kHz (unless otherwise noted)

#### output section

PARAMETER		TEST COND	TL49	UNIT			
			MIN	TYP <sup>†</sup>	MAX		
Collector off-state current		V <sub>CE</sub> = 40 V,	V <sub>CC</sub> = 40 V		2	100	μΑ
Emitter off-state current		$V_{CC} = V_{C} = 40 \text{ V},$	V <sub>E</sub> = 0			-100	μΑ
Callactor emitter acturation valtage	Common emitter	V <sub>E</sub> = 0,	$I_C = 200 \text{ mA}$		1.1	1.3	V
Collector-emitter saturation voltage	Emitter follower	$V_{O(C1 \text{ or } C2)} = 15 \text{ V},$	$I_E = -200 \text{ mA}$		1.5	2.5	V
Output control input current		$V_I = V_{ref}$				3.5	mA

 $<sup>^{\</sup>dagger}$  All typical values except for temperature coefficient are at  $T_A$  = 25°C.

## dead-time control section (see Figure 1)

PARAMETER	TEST CONDITIONS	TL494C, TL494I TL494Y			TL494M			UNIT
		MIN	TYP <sup>†</sup>	MAX	MIN	TYP <sup>†</sup>	MAX	
Input bias current (DEAD-TIME CTRL)	V <sub>I</sub> = 0 to 5.25 V		-2	-10		-2	-10	μА
Maximum duty cycle, each output	$\begin{aligned} & V_I \text{ (DEAD-TIME CTRL)} = 0, \\ & C_T = 0.1 \ \mu\text{F},  & R_T = 12 \ k\Omega \end{aligned}$		45%			45%	50%*	
Innut threehold valte as (DEAD TIME CTDL)	Zero duty cycle		3	3.3		3	3.3	V
Input threshold voltage (DEAD-TIME CTRL)	Maximum duty cycle	0		, and the second	0*			V

<sup>\*</sup> On products compliant to MIL-STD-883, Class B, this parameter is not production tested.

## PWM comparator section (see Figure 1)

PARAMETER	TEST CONDITIONS	TL494C, TL494I TL494M, TL494Y			UNIT
		MIN	TYP†	MAX	
Input threshold voltage (FEEDBACK)	Zero duty cycle		4	4.5	V
Input sink current (FEEDBACK)	V (FEEDBACK) = 0.7 V	0.3	0.7	·	mA

<sup>†</sup> All typical values except for temperature coefficient are at  $T_A = 25$ °C.

## total device

PARAMETER	TEST CONDITIONS		TL494C, TL494I TL494Y			TL494M			UNIT
			MIN	TYP†	MAX	MIN	TYP <sup>†</sup>	MAX	
Standby supply current RT = V <sub>ref</sub> , All other inputs and out	RT = V <sub>ref</sub> ,	V <sub>CC</sub> = 15 V		6	10		6	21	mA
	All other inputs and outputs open	V <sub>CC</sub> = 40 V		9	15		9	26	IIIA
Average supply current	V <sub>I</sub> (DEAD-TIME CTRL) = 2 V,	See Figure 1		7.5			7.5		mA

<sup>&</sup>lt;sup>†</sup> All typical values except for temperature coefficient are at  $T_A = 25$ °C.

<sup>&</sup>lt;sup>†</sup> All typical values except for temperature coefficient are at  $T_A = 25$ °C.

## TL494C, TL494I, TL494M, TL494Y PULSE-WIDTH-MODULATION CONTROL CIRCUITS

SLVS074A - JANUARY 1983 - REVISED AUGUST 1995

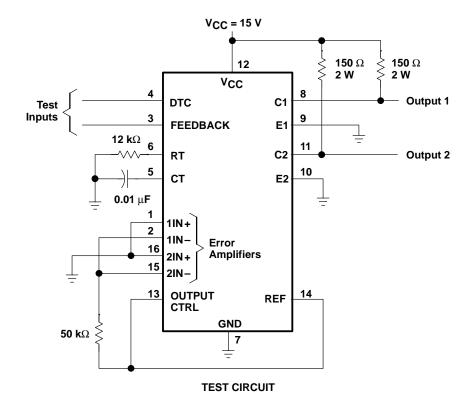
electrical characteristics over recommended operating free-air temperature range,  $V_{CC}$  = 15 V, f = 10 kHz (unless otherwise noted) (continued)

## switching characteristics, $T_A = 25^{\circ}C$

PARAMETER	TEST CONDITIONS		TL494C, TL494I TL494Y			TL494M		
		MIN	TYP <sup>†</sup>	MAX	MIN	TYP <sup>†</sup>	MAX	
Rise time	Common-emitter configuration, See Figure 3		100	200		100	200*	ns
Fall time	Common-emitter configuration, See Figure 3		25	100		25	100*	ns
Rise time	Emitter-follower configuration, See Figure 4		100	200		100	200*	ns
Fall time	Emiliarionower comiguration, occinique 4		40	100		40	100*	ns

<sup>\*</sup> On products compliant to MIL-STD-883, Class B, this parameter is not production tested. † All typical values except for temperature coefficient are at  $T_A = 25^{\circ}C$ .

## PARAMETER MEASUREMENT INFORMATION



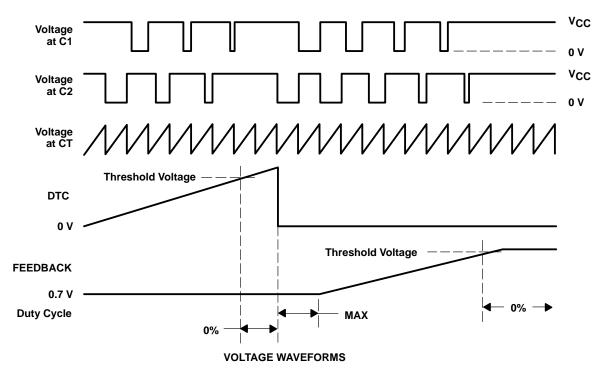


Figure 1. Operational Test Circuit and Waveforms



## PARAMETER MEASUREMENT INFORMATION

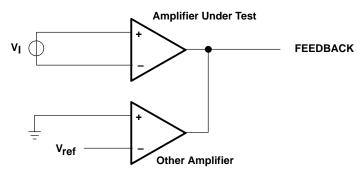
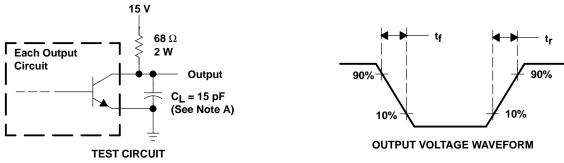
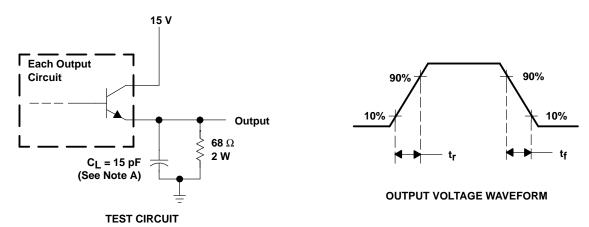


Figure 2. Amplifier Characteristics



NOTE A.  $\,$  C<sub>L</sub> includes probe and jig capacitance.

Figure 3. Common-Emitter Configuration



NOTE A. C<sub>L</sub> includes probe and jig capacitance.

Figure 4. Emitter-Follower Configuration

## **TYPICAL CHARACTERISTICS**

## OSCILLATOR FREQUENCY AND FREQUENCY VARIATION†



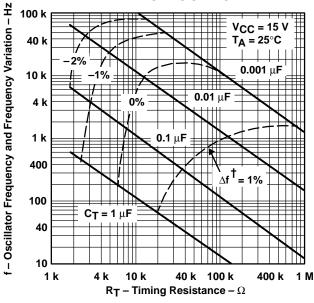


Figure 5

## AMPLIFIER VOLTAGE AMPLIFICATION

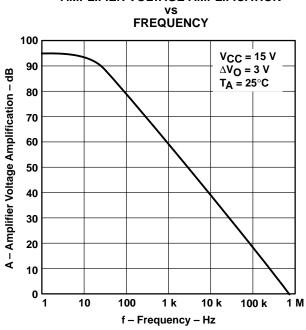




Figure 6

<sup>&</sup>lt;sup>†</sup> Frequency variation ( $\Delta f$ ) is the change in oscillator frequency that occurs over the full temperature range.

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